

Pressure-induced concomitant topological and metal-insulator quantum phase transitions in $\text{Ce}_3\text{Pd}_3\text{Bi}_4$

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Abstract

The electronic property and magnetic susceptibility of $\text{Ce}_3\text{Pd}_3\text{Bi}_4$ were systemically investigated from 18 K to 290 K for varying values of cell-volume using dynamic mean-field theory coupled with density functional theory. By extrapolating to zero temperature, the ground state of $\text{Ce}_3\text{Pd}_3\text{Bi}_4$ at ambient pressure is found to be a correlated semimetal due to insufficient hybridization. Upon applying pressure, the hybridization strength increases and a crossover to Kondo insulator is observed at finite temperatures. The characteristic temperature signaling the formation of Kondo singlet, as well as the characteristic temperature associated with f -electron delocalization-localization change, simultaneously vanishes around a critical volume of $0.992V_0$, suggesting that such metal-insulator transition is possibly associated with a quantum critical point. Finally, the Wilson's loop calculations indicate that the Kondo insulating side is topologically trivial, thus a topological transition also occurs across the quantum critical point.

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I. INTRODUCTION

Kondo insulator is a prototypical strongly correlated quantum matter involving $4f$ or $5f$ electrons. At higher temperatures, the system is metallic since the f -electron-derived local moments do not strongly couple to conduction electrons. Upon cooling, an energy gap opens at the Fermi energy, due to the formation of Kondo singlets between the local moments and conduction electrons. In the meantime, the electronic states experience an incoherent to coherent crossover. In the above process, the hybridization strength $\Gamma \propto N_0|V|^2$, with V being the hybridization interaction and N_0 conduction electron density of states at the Fermi energy, is of particular importance, since the Kondo coupling strength depends directly on this quantity as $J_K \propto |V|^2/U$ with U the Coulomb interaction on f -electrons. According to the famous Doniach phase diagram [1], this coupling leads to a conduction-electron mediated Ruderman-Kittel-Kasuya-Yosida (RKKY) interaction, which in turns competes with the Kondo coherence effect. They are characterized by respective energy scale, T_{RKKY} and T_K . Therefore, if V is too small, the formation of Kondo singlet shall fail and lead to a magnetic ground state instead. Apart from temperature, the strength of hybridization can be tuned via chemical doping, external pressure and magnetic field alternatively. These nonthermal parameters therefore provide control over competing ground states, and may realize quantum critical phenomena [2–4]. More interestingly, when the competing ground states are associated with different topological invariants, a topological quantum phase transition is achieved. It has been proposed that the critical point of a topological quantum phase transition can host novel semimetal states, which exhibit non-Fermi liquid or marginal Fermi liquid behavior [5–8].

The archetypal Kondo insulator $\text{Ce}_3\text{Pt}_3\text{Bi}_4$ was comprehensively and systematically studied in the past several decades [9–13], and regained much attention recently due to its possible connection with topological Kondo insulators [14–16]; while an isoelectronic substitution of $5d$ -element Pt with $4d$ element Pd, the possible nontrivial topological properties and the metallic ground state with a large quasiparticle mass enhancement have been studied in $\text{Ce}_3\text{Pd}_3\text{Bi}_4$ [17–20]. Further experiments, however, show that $\text{Ce}_3\text{Pd}_3\text{Bi}_4$ exhibits a weak activation behavior of $\Delta \sim 0.4$ meV which can be suppressed above magnetic field of $B_c \approx 11$ T, suggesting that the system may be very close to a metal-insulator transition point [21]. Theoretically, the dynamical mean-field theory (DMFT) study revealed that the $\text{Ce}_3\text{Pd}_3\text{Bi}_4$

compound is a topological nodal line semimetal, whose metallic behaviour persists down to 4 K, while the $\text{Ce}_3\text{Pt}_3\text{Bi}_4$ compound is a trivial Kondo insulator with an indirect gap of 6 meV below 18 K [19]. A sharp difference between the hybridization functions of $\text{Ce}_3\text{Pt}_3\text{Bi}_4$ and $\text{Ce}_3\text{Pd}_3\text{Bi}_4$ is observed in the DFT+DMFT study [19], and in DFT study as well [22]. Nevertheless, it has yet to be determined whether the ground state of $\text{Ce}_3\text{Pd}_3\text{Bi}_4$ compound is a small gap insulator or an exotic metal. Although the ground state study of this compound is of significant importance, an accurate DMFT calculation at sufficiently low temperature is extremely time-consuming and unrealistic. Here, we take an alternative approach by performing a series of calculations at different temperatures and pressure. As a result, the magnitude of hybridization energy gap, hybridization strength, valence band edge E_v , quasiparticle weight Z , as well as local magnetic susceptibility can be studied as functions of temperature and pressure. In addition, the ground state properties can also be obtained by extrapolating temperature-dependent electronic and magnetic properties of $\text{Ce}_3\text{Pd}_3\text{Bi}_4$ to zero temperature.

II. RESULTS

A. Electronic structure of $\text{Ce}_3\text{Pd}_3\text{Bi}_4$

The momentum-resolved spectra functions $A(\omega, \mathbf{k})$ between $E_F - 0.3$ eV to $E_F + 0.2$ eV at $T=29$ K, 58 K and 116 K for 90% V_0 , 94% V_0 and 98% V_0 are shown in Figure 1 respectively. V_0 is the experimental unit cell volume at ambient pressure. A gradual change of spectra function from incoherent to coherent behavior near the Fermi level is evident with decreasing temperature and increasing pressure (from the top-left to the right-bottom panel in Figure 1). For the 98% compressed Pd-compound (the upper panels in Figure 1), the spectra functions unequivocally display a blurred region in a wide temperature range from 116 K down to 29 K, indicative of the incoherent scattering at higher temperatures (see Supplementary Note 1 for details). Increasing the pressure (94% V_0 compound), the spectra become sharper near the Fermi level. In particular, a small energy gap appears in the very vicinity of E_F at the temperature of 29 K. For the most compressed compound (90% V_0) considered in this work, the energy gap can be identified at even higher temperature, implying the external pressure has driven the system away from the metallicity. It is worth

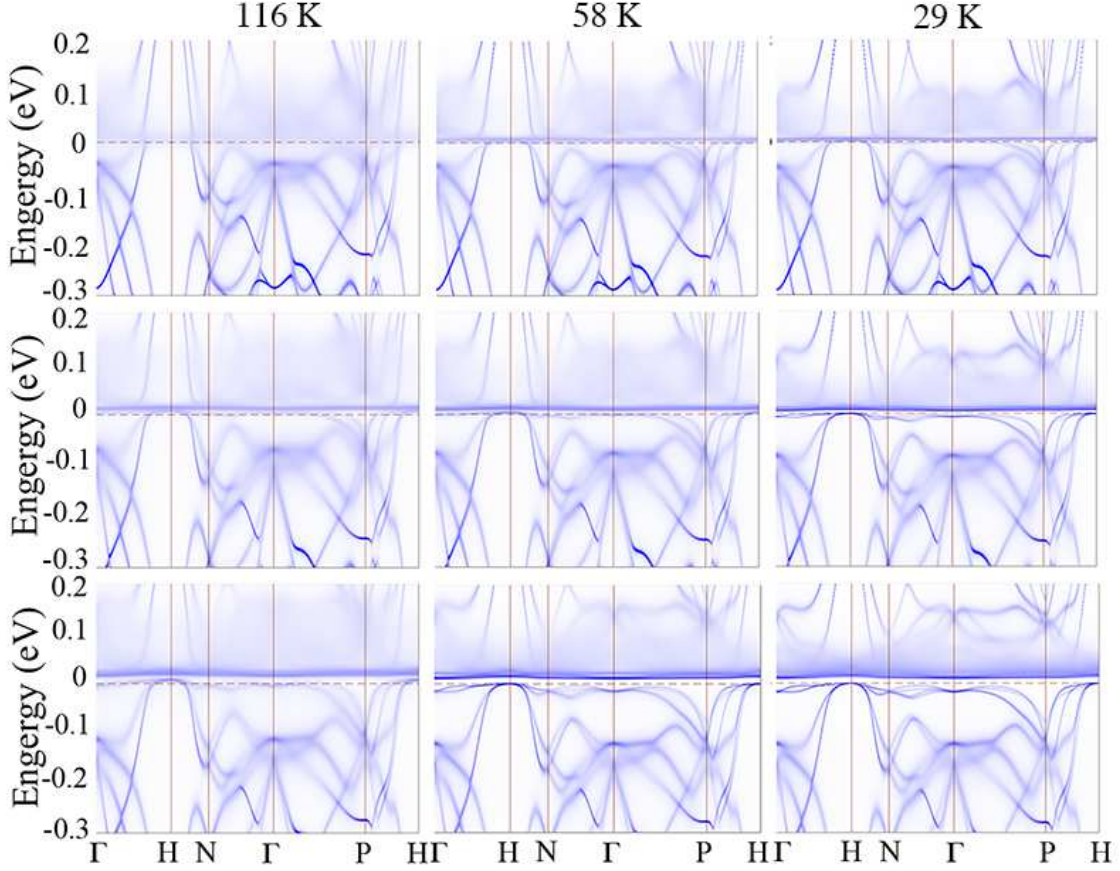


FIG. 1. Momentum-resolved spectral function of $\text{Ce}_3\text{Pd}_3\text{Bi}_4$ from DFT+DMFT at 29 K, 58 K and 116 K for various cell-volumes respectively. The panels from top to bottom are 98%, 94% and 90% compressed V_0 , respectively. From the top-left panel to the right-bottom panel, an energy gap around the Fermi level gradually opens under the lattice shrinking and upon cooling.

noting that the spectra of 90% compressed $\text{Ce}_3\text{Pd}_3\text{Bi}_4$ compound at 29 K resembles that of $\text{Ce}_3\text{Pt}_3\text{Bi}_4$ at 18 K [19], suggesting similar effect of external pressure and isoelectronic substitution by Pt, in agreement with previous study [23].

To obtain insights into the formation of energy gap upon reducing temperature and increasing external pressure, the hybridization function and integrated spectra density were illustrated in Figure 2. In general the intensities of hybridization function (both the real and imaginary part) are gradually enhanced as the cell-volume decreases. Simultaneously, the peak position is shifted away from the Fermi level, corresponding to the transfer of spectral weight from E_F to the gap edges. This is the typical behavior of the charge gap formation due to the hybridization between the f -electron and conduction electrons [10, 24]. The change in

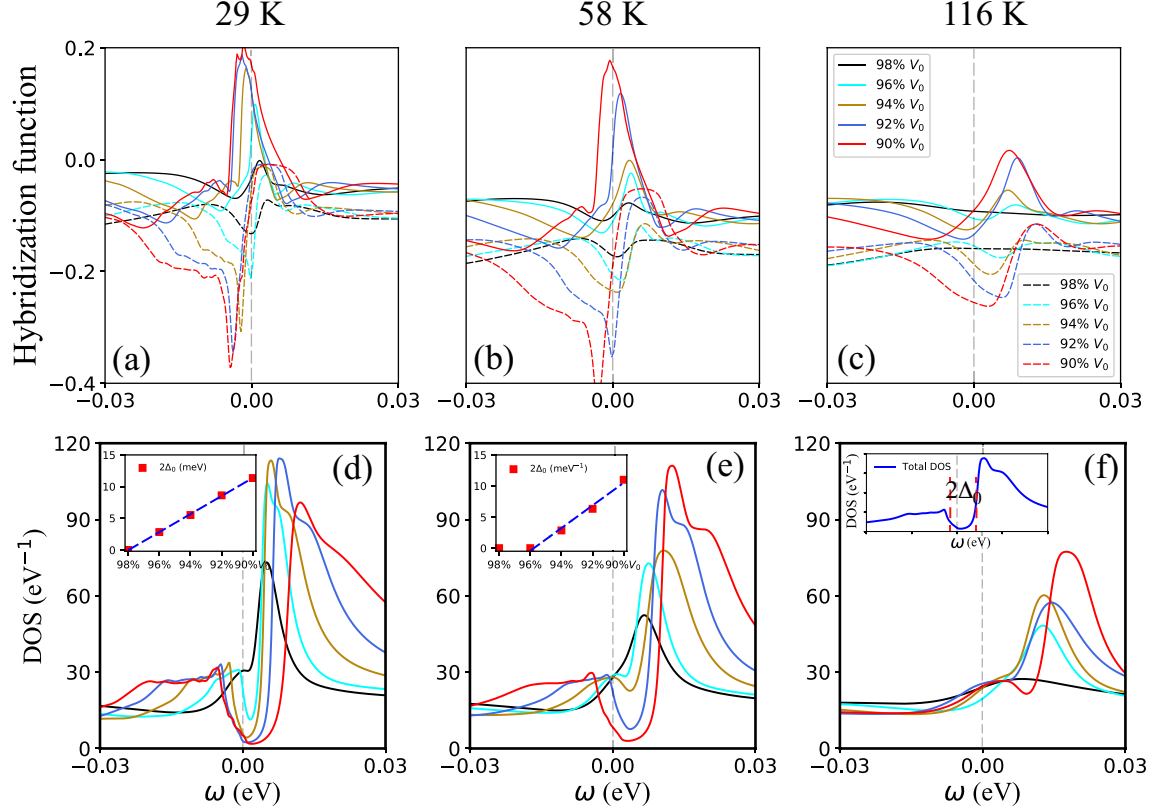


FIG. 2. Pressure dependence of hybridization function and local spectra density. (a-c) The real (solid lines) and imaginary (dashed lines) part of hybridization function. (d-f) the integrated spectra density at 29 K, 58 K and 116 K, for 98%, 96%, 94%, 92% and 90% compressed cell-volume, respectively. The magnitude of the energy gap is plotted as the function of cell-volume shown in the inset of d and e. The gap-size is evaluated from the half height of the maximal intensity at the gap edge below E_F to the minimal intensity value inside the gap as schematically illustrated in the inset of (f). The black dashed line in the inset of (f) marks the valence bands edge E_v .

hybridization function is consistent with the integrated spectra density change as shown in Figure 2 (d-f). The integrated spectra density at E_F initially decreases under the pressure, then begins to show a small dip for 94% compressed Pd-compound, and finally forms a broad U-shaped gap for 90% compressed Pd-compound at 29 K. Such pressure-induced behavior, however, is less obvious at 116 K due to the collapse of energy gap at high temperature. If we evaluate the gap size Δ_0 , as illustrated in the insets of Figure 2, by the energy interval from the half-height of the maximal intensity at the gap edge below E_F to the minimum

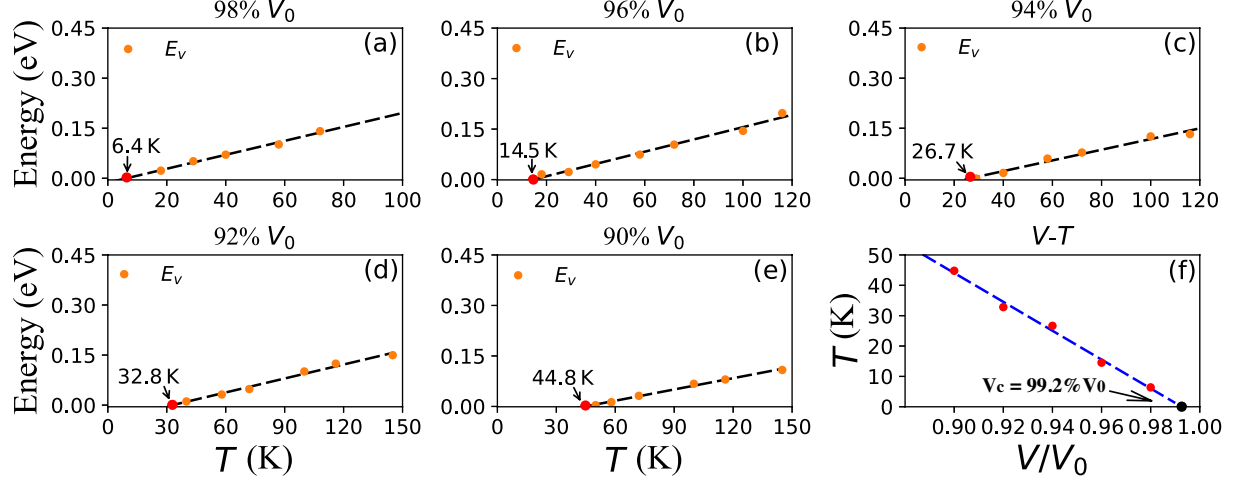


FIG. 3. Temperature and pressure dependence of valence band edge. (a-e) Temperature evolution of valence band edge E_v at 98%, 96%, 94%, 92% and 90% of the equilibrium volume V_0 , respectively. The tops of the valence bands relative to the Fermi level are marked as blue (orange) dots. The grey dashed lines are linear fittings to E_v . The black arrow indicates the extrapolated critical temperatures T_1 (marked as red dots) when the E_v cuts the Fermi level. (f) Pressure evolution of T_1 . The red dots mark T_1 from (a-e). The blue dashed line is the linear extrapolation to zero temperature.

intensity value inside the gap, Δ_0 can be well fitted with a linear function to external pressure (cell-volume) at both 29 K and 58 K. Similar linear pressure dependence of energy gap was previously reported in $\text{Ce}_3\text{Pt}_3\text{Bi}_4$ [12]. In addition, for a specific pressure (volume), Δ_0 is also smoothly dependent on the temperature. Hence the system continuously goes through a crossover from a metallic regime to an insulating regime upon cell-volume compressing at finite temperature.

Having qualitatively established the presence of metal-insulator crossover below some certain characteristic temperature at various compressed cell-volumes, we now address the question whether the ground state ($T \rightarrow 0$) of $\text{Ce}_3\text{Pd}_3\text{Bi}_4$ at ambient conditions is characterized by the Kondo insulating or f -electron-incoherent metallic states. As mentioned above, the spectral intensity at E_F gradually reduces upon cooling, resulting in a red-shift of valence bands edge E_v due to the formation of energy gap. Once the top of valence band shifts below E_F , the Fermi level E_F is pinned inside the gap, leading the system towards the insulating regime when $T > 0$ K. Therefore, a characteristic temperature T_1 can be defined

when E_v coincides with E_F . Below T_1 , the electronic states around the Fermi level shall eventually become coherent, and a true gap shall appear at sufficiently low temperature. Then we examine the shift of valence bands edge E_v relative to the Fermi level for various compressed cell-volumes in the temperature range from 18 K to 116 K. The calculated results are shown in Figure 3 (a-e). By extrapolating to zero temperature, we find the valence band edge cuts the Fermi level at T_1 of 6.4 K, 14.5 K, 26.7 K, 32.8 K and 44.8 K for 98%, 96%, 94%, 92% and 90% V_0 , respectively. It indicates that the ground states are insulating at 0 K for the corresponding cell-volume. In Figure 3 (f), we show the varying of T_1 as a function of cell-volume. The T_1 linearly decreases as the lattice expands, which is in line with the aforementioned linear suppression of energy gap under small increasing of cell-volume [21]. The temperature scale T_1 eventually disappears at 99.2% V_0 (corresponding to the hydrostatic pressure of 1.1 GPa, see Supplementary Note 2), implying that the insulating phase cannot be stabilized at 0 K when the cell-volume is larger than this value.

B. Magnetic susceptibility

To further verify this, we have also calculated the local magnetic susceptibility χ_{loc} for different cell-volumes. The results are shown in Figure 4 (also see Supplementary Note 3). Upon lattice shrinking, the Curie-like susceptibility gradually turns to be Pauli-like with much weaker temperature dependence, indicating the reduction of local moment due to the Kondo screening. The quantity T^* evaluated from the maximal of χ_{loc} is the characteristic temperature below which the local moment of f -electron and the conduction electron form an entangle state, e.g. the Kondo singlet, and the system starts entering into the coherent regime with the Fermi-liquid behavior. As the cell-volume decreases, T^* gradually increases, signaling the tendency of f -electron coherence from a low pressure phase to a high pressure phase [25, 26]. In the inset of Figure 4, we show T^* as a function of cell-volume, which is qualitatively similar to the previous experimental observations [18]. Intriguingly, T^* also approaches to zero at $\sim 99\%$ V_0 , concomitant with the disappearance of the delocalization-localization crossover temperature, T_1 , at the same cell-volume. This strongly suggests that, under the ambient pressure, the Ce-4*f*-electrons in $\text{Ce}_3\text{Pd}_3\text{Bi}_4$ compound remains localized even at zero temperature.

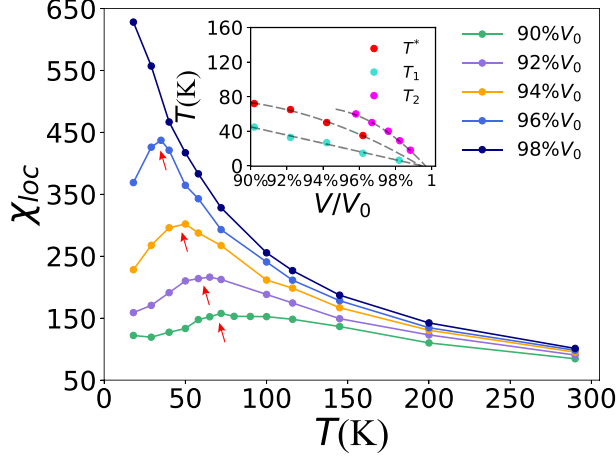


FIG. 4. Temperature dependence of local magnetic susceptibility χ_{loc} for various compressed cell-volumes. The inset shows the temperature versus pressure phase diagram. The characteristic temperature T^* (marked with the red dots) associated with the formation of Kondo singlet, is corresponding to the maximums of the local magnetic susceptibility marked with red arrows in the main figure. Correspondingly, we show the $1/\chi_{loc}$ in the Supplementary Note 3. In comparison, the pressure evolution of T_1 and T_2 from Figure 3 (f) and Supplementary Figure 5(a) are illustrated in the inset as well. The dashed line indicates the gradual suppression trend of T^* upon lattice compression. Note that for 98% V_0 Pd-compound, no maximum of χ_{loc} can be identified down to 18 K.

C. Upper limit of crossover temperature

Furthermore, we can also estimate another characteristic temperature T_2 at which the energy gap Δ_0 begins to develop around E_F . It is worth noting that the presence of such a gap at finite temperatures does not guarantee an insulating phase because the system is susceptible to the incoherent in-gap state and the alignment of the Fermi level due to thermal effect. Therefore, it poses an upper limit of corresponding to f -electron localization-delocalization crossover temperature. However, as the temperature approaches 0, the thermal effect diminishes, and the extrapolation also approaches P_c at 1.1 GPa (Figure 4 inset, as well as Supplementary Note 4).

III. DISCUSSION

The following remarks and discussions are in order: Firstly, as we have stated previously, the effect of external pressure is similar to the isoelectronic substitution by Pt. In fact, previous DFT study has shown that the radial extent of Pd(Pt)-4d(5d) shall affect the hybridization strength [22]. Therefore, the localization-delocalization transition may also be realized with Pt-substitution. Secondly, we have observed scaling behavior in the Kondo insulating regime between unrenormalized energy gap Δ_0/Z and the maximum of hybridization function $\text{Im}[\Gamma_{\text{max}}(\omega)]$, defined as the peak value of imaginary part of hybridization function near the Fermi level, which suggests a critical hybridization strength of $\text{Im}[\Gamma_{\text{max}}(\omega)] \approx -0.15$ eV. This is also consistent with the critical P_c around 1 GPa (see Supplementary Note 4 for details). Thirdly, it is informative to mention that the Hubbard U has moderate influence on the critical value of the gap as well. Since the larger value of U yields more localized Ce-4f moment, which is in turn harmful to a finite magnitude of energy gap, a larger/smaller U would result in a slightly larger/smaller critical pressure P_c . Nevertheless, the controversial experimental results [18, 21] indicate the close proximity of the ambient system close to the critical pressure, which is arguably accessible with small pressure. It is also worth noting that similar effect of f -electrons localization-delocalization can also be achieved by applying magnetic field in addition to external pressure, which may serve as an explanation for the observed simultaneous vanishing of T^* and T_1 at critical magnetic field $B_c \approx 11$ Tesla [21]. Finally, at the Kondo insulating regime, we have employed topological Hamiltonian [27, 28] and Wilson loop method [29] to show that the system is topologically trivial (see Supplementary Note 5). Since at the f -electron-incoherent metallic state, the system is topological nodal-line semimetals as suggested in Ref. [19], it can be inferred that the f -electron localization-delocalization transition is accompanied by a topological phase transition as well.

In conclusion, we have performed a comprehensive DFT+DMFT study of pressure/temperature dependent electronic structure of $\text{Ce}_3\text{Pd}_3\text{Bi}_4$. At ambient pressure, the ground state of $\text{Ce}_3\text{Pd}_3\text{Bi}_4$ at 0 K is found to be metallic due to insufficient hybridization between the Ce-4f electron and conduction electrons. As the pressure increases, the hybridization enhances, and a metal-insulator transition occurs around 99% V_0 . Using the topological Hamiltonian and Wilson loop method, the pressurized insulating phase is found to be a topologically

trivial Kondo insulator. This leads to the observation that the metal-insulator transition is accompanied by a topological transition as well. Our results suggest that a possible topological quantum critical point may be achieved by applying pressure in $\text{Ce}_3\text{Pd}_3\text{Bi}_4$.

IV. METHODS

To describe the electron correlation and magnetic fluctuation of Ce-compounds, the combination of density function theory (DFT) and DMFT [30, 31] was employed. The DFT part was performed with the full-potential linear augmented plane-wave method implemented in the Wien2k package [32] with generalized gradient approximation[33]. The continuous-time Monte Carlo method (CTQMC) [34] was used as the impurity solver in its fully self-consistent version of DFT+DMFT. The Coulomb interaction $U = 6.0$ eV and Hund's coupling $J = 0.7$ eV were considered for Ce-4*f* orbitals (see Supplementary Note 1 for details). Since the simulated pressures are rather small, the internal atomic positions were kept the same as those under the ambient condition when changing the lattice constant to simulate the external pressure, The topological Hamiltonian $h_t(\mathbf{k}) = h_0(\mathbf{k}) + \Sigma(\omega = 0)$ can be obtained after the self-consistent DFT+DMFT calculations. The zero frequency self-energy $\Sigma(0)$ was also extrapolation to zero temperature. Both $h_0(\mathbf{k})$ and $\Sigma(0)$ are symmetrized with the WannSymm code [35].

DATA AVAILABILITY

The data that support the findings of this study are available from the corresponding author upon reasonable request.

CODE AVAILABILITY

The latest WannSymm code is available on <http://github.com/ccao/WannSymm>.

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AUTHOR CONTRIBUTIONS

C.C. and J.-X.Z. initiated this work; C.X. and C.C. performed the calculations and were responsible for the data analysis; J.-X.Z. participated in the interpretation of numerical results. All authors contributed to the manuscript.

COMPETING INTERESTS

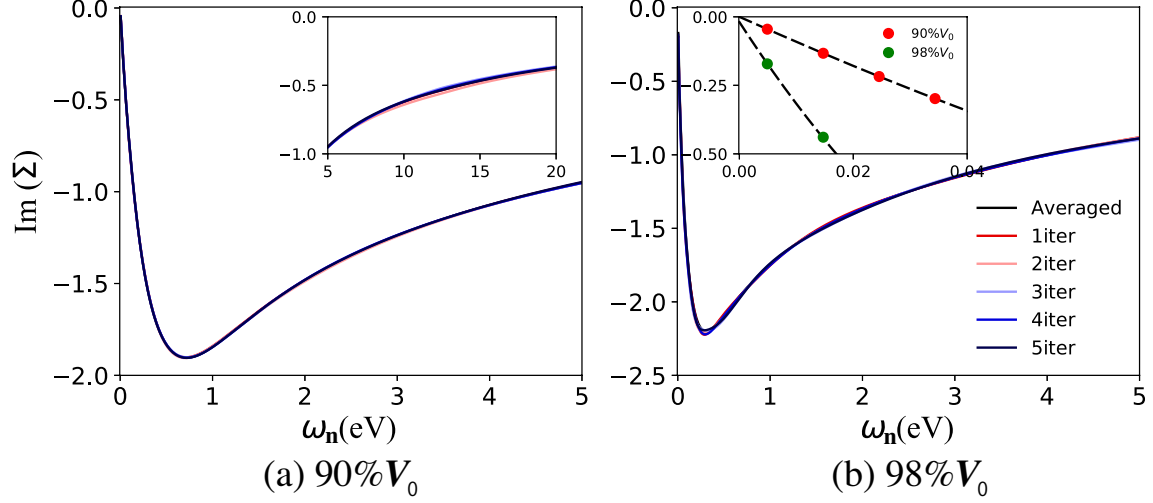
The authors declare no competing interests.

SUPPLEMENTARY NOTES

1. DFT+DMFT CALCULATION DETAILS

The DFT calculation was performed based on the full-potential linear augmented-plane-wave (FP-LAPW) method as implemented in the Wien2K package [32]. The Perdew, Burke, and Ernzerhof parameterization of generalized gradient approximation to the exchange correlation functional [33] was used. Through the calculation, the number of plane waves was set to $RK_{max} = 9$ and a $12 \times 12 \times 12$ Γ -centered K-mesh was used to perform the Brillouin zone (BZ) integration to ensure the convergency.

The charge-self-consistent DFT+DMFT calculation was also performed within FP-LAPW basis set on a $12 \times 12 \times 12$ Γ -centered K-mesh. The continuous time Monte Carlo method (CTQMC) was applied to solve the Anderson impurity problem with the full Coulomb interaction matrix in its rotationally invariant Slater form. We consider the Coulomb interaction $U = 6.0$ eV and Hund's coupling $J = 0.7$ eV for the partially filled Ce-4*f* orbitals. The nominal double counting scheme was considered with $n_f^0 = 1$ as the nominal occupancy of the ionic state. The spin-orbit coupling (SOC) was considered for the Ce-4*f* orbitals. The crystalline electric field (CEF) splitting is one order of magnitude smaller than SOC and thus it is ignored inside the impurity solver. Hence, the local basis for the CTQMC were projected to $|5/2\rangle$ and $|7/2\rangle$. To check the CEF effect, we did a test in our previous study [19] by running an additional step of DMFT self-consistency calculations with self-energy projected to distinct m_J states, after the charge self-consistency was achieved. The results suggest that the CEF is small, and its effect to spectral function is negligible even at 4 K. Since in our current study, the lowest simulated temperature is much higher, we do not expect significant CEF effect. We note that a full charge self-consistency calculation with distinct m_J -dependent self-energy components could also be performed, as reported in a recent work on Ce₃Bi₄Pt₃ by Pickem *et al.*[23]. In the present work, we chose the energy range of hybridization from $E_F - 10$ eV to $E_F + 10$ eV, where the Pd-4*d*, Bi-6*p*, Ce-4*f* and Ce-5*d* orbitals are included. After the DFT+DMFT calculation is well converged on the imaginary axis, we apply the maximum entropy method to do analytical continuation. The spectral function is then obtained on the real axis with a $24 \times 24 \times 24$ Γ -centred K-mesh. To accurately obtain the valence (conduction) band edge (Fig. 3 in main



Supplementary Figure. 5. Imaginary part of Matsubara self-energy $\Sigma(i\omega_n)$ of $J = 5/2$ state at 18 K. (a) 90% compressed cell-volume. (b) 98% compressed cell-volume. Inset of (a) shows the high frequency tail of $\Sigma(i\omega_n)$ of 90% compressed compound. The low frequency behavior of $\Sigma(i\omega_n)$ for both 90% and 98% V_0 are shown in the inset of (b). The imaginary part of $\Sigma(i\omega_n)$ is extrapolated to zero-frequency indicated by the grey dashed line. The magnitude of extrapolated value $\Sigma(i\omega_n \rightarrow 0)$ is 21.3 meV (less than 1 meV) for 98% V_0 (90% V_0).

text), we employed an even more dense K-mesh with $48 \times 48 \times 48$ points in the full BZ.

We performed the DMFT calculations for 90%, 92%, 94%, 96% and 98% compressed cell-volume in the temperature range from 18 K to 290 K. Throughout the calculation, we used 96 CPU-cores and the QMC steps ranging from 2×10^8 (for 290 K) to 8×10^8 (for 18 K) for each core. After the charge and energy are sufficiently converged with 25-60 DMFT iterations, we have additional 5 DMFT iterations to average the obtained self-energy in Matsubara frequency (Fig. 5). As shown in Fig. 5 (a-b), at the low frequency, the self-energy $\Sigma(i\omega_n)$ of last 5 iterations and the averaged result are nearly indistinguishable, which also demonstrates the sufficient convergence of $\Sigma(i\omega_n)$ in our calculation. When $\omega_n \rightarrow 0$, the self-energy $\Sigma(i\omega_n)$ for 90% compressed $\text{Ce}_3\text{Pd}_3\text{Bi}_4$ approaches zero. For 98% compressed compound, however, $\Sigma(i\omega_n)$ is extrapolated to a small finite value.

The self-energy $\Sigma(\omega)$ on the real axis can be obtained with maximum entropy method. We illustrate the imaginary part of $\text{Im}[\Sigma_{5/2}]$ at $T=29$ K, 58 K and 116 K for various cell-volume, as well as the parabolic fitting results in Fig. 6. For the metallic system, the fitting is confined within $[-T, T]$, where T is the temperature at which the calculation is performed.

While for the gapped system, the fitting is taken inside the gap. In Fig. 6, $\text{Im}[\Sigma_{5/2}]$ can be well fitted with a parabolic function $\alpha(\omega - \omega_0)^2 + \Sigma_0$ in the low frequency region. We find the Σ_0 systematically varies as the function of temperature and cell-volume. For 98% V_0 , the Σ_0 is substantially large in comparison with the gap-size, implies the incoherent non-Fermi liquid behaviour for all the temperature region on display. For 90% V_0 at 29 K, the gap-size is already one order larger than Σ_0 , indicating the coherent Fermi liquid behaviour of current system. Such a systematic trend (from incoherent to coherent region) can also be found in the momentum-resolved spectral function in Fig. 1 in the main text.

2. Pressure fitting

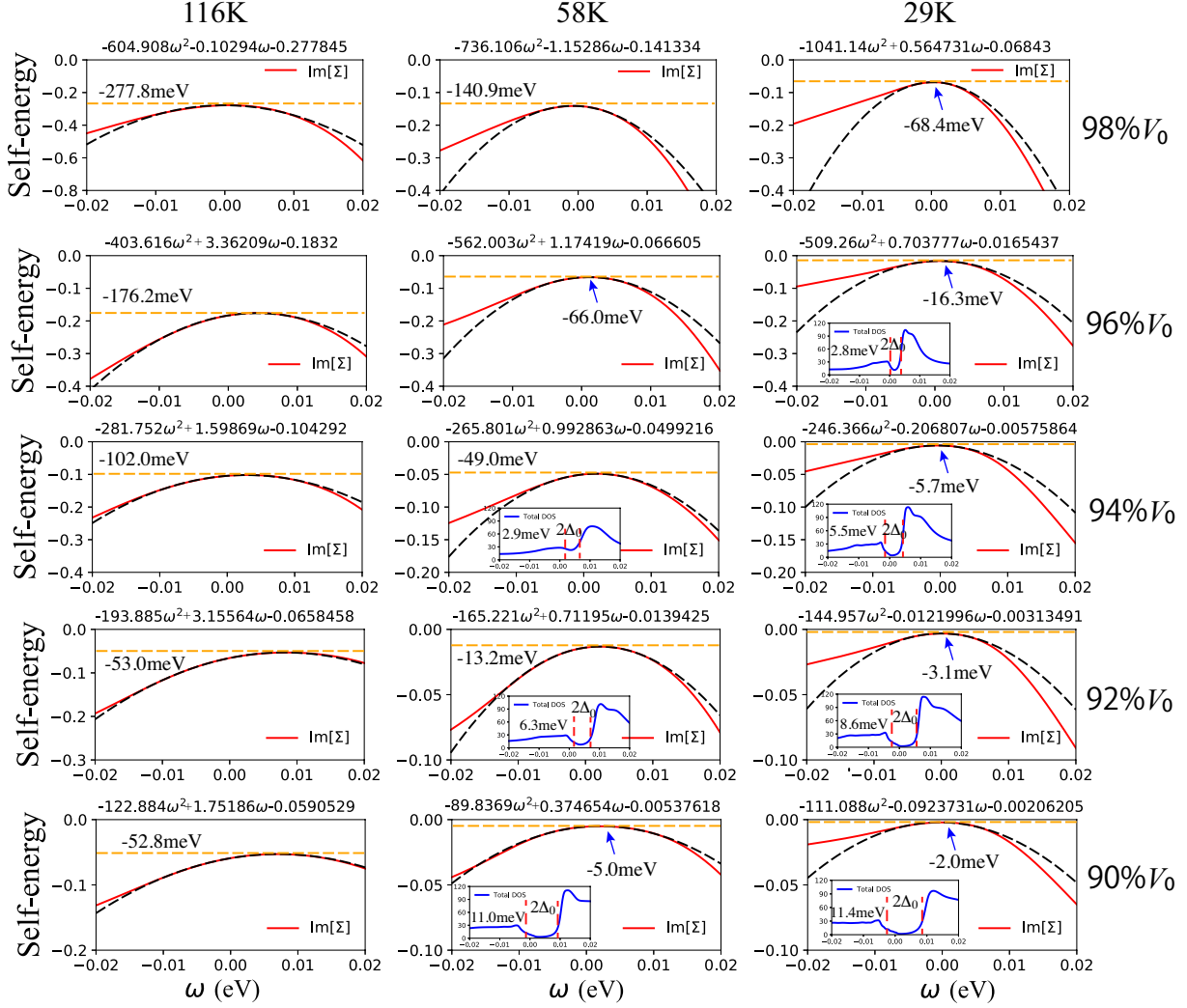
In Fig. 7 (a-b), we show the total energy and pressure as a function of cell-volume. The total energy for various cell-volumes was obtained from the average value of last 5 DMFT iterations after the calculation was well converged. The pressure was fitted by using the Murnaghan equation of state,

$$P(V) = \frac{K_0}{K'_0} \left[\left(\frac{V}{V_0} \right)^{-K'_0} - 1 \right]$$

where V_0 is the equilibrium volume, K_0 is the bulk modulus and K'_0 is its first derivative with respect to the pressure. K_0 and K'_0 were fitted from volume dependence of total energy curve. The obtained results are also cross-checked with Birch–Murnaghan fitting method. The corresponding values are listed in Table. I. The critical cell-volume V_c (99.2% V_0) are marked with red star in Fig. 7 (b). It is corresponding to the external pressure of 1.1 GPa for both fitting method.

3. Inverse local magnetic susceptibility

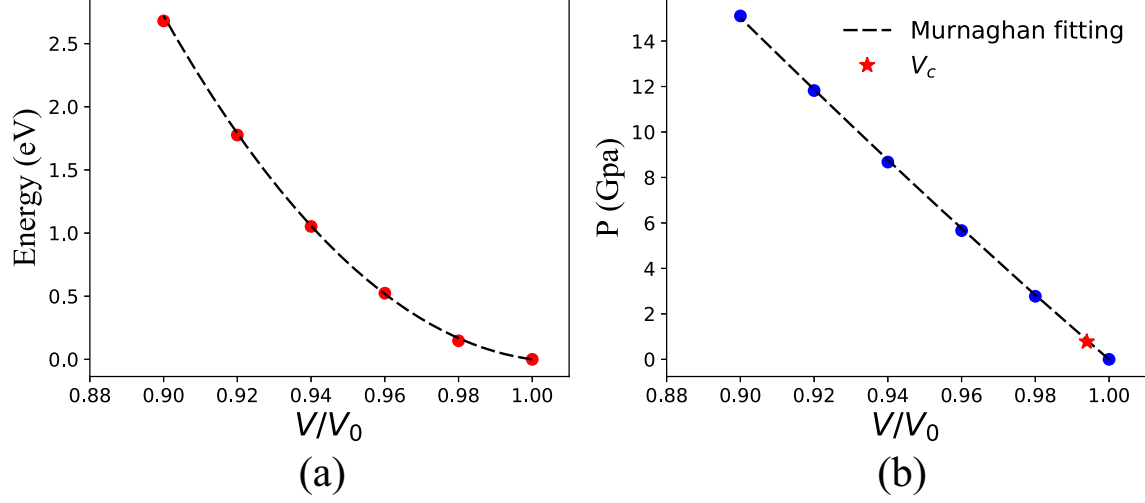
In Fig. 8, we show the temperature dependence of inverse local magnetic susceptibility χ_{loc}^{-1} for 90%, 92%, 94%, 96% and 98% V_0 compounds. For 98% V_0 , a linearly temperature-dependent of χ_{loc}^{-1} can be estimated even at low temperature. As the cell volume increases, the χ_{loc}^{-1} gradually deviates from the linearly temperature dependence. The T^* (Marked with red arrows in Fig. 8) can also be roughly estimated as the temperature when the χ_{loc}^{-1} begins to deviate from the linearity.



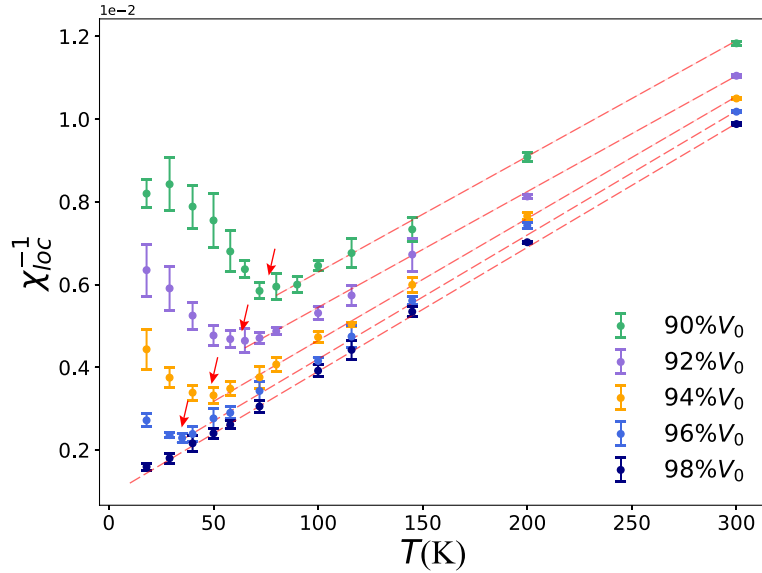
Supplementary Figure. 6. Imaginary part of self-energy $\Sigma(\omega)$ on real axis at 29 K, 58 K and 116 K for various cell-volume. The red solid lines denotes the imaginary part of self-energy of $J = 5/2$ state, $\Sigma_{5/2}$. The dashed lines are the parabolic fitting to $\Sigma_{5/2}$. The orange dashed lines are guides for eye to show the Σ_0 from fitting. For the gapped system, we show the local spectral function in the insets as well.

4. Pressure and temperature dependent local spectra density, gap, renormalized factor and hybridization function

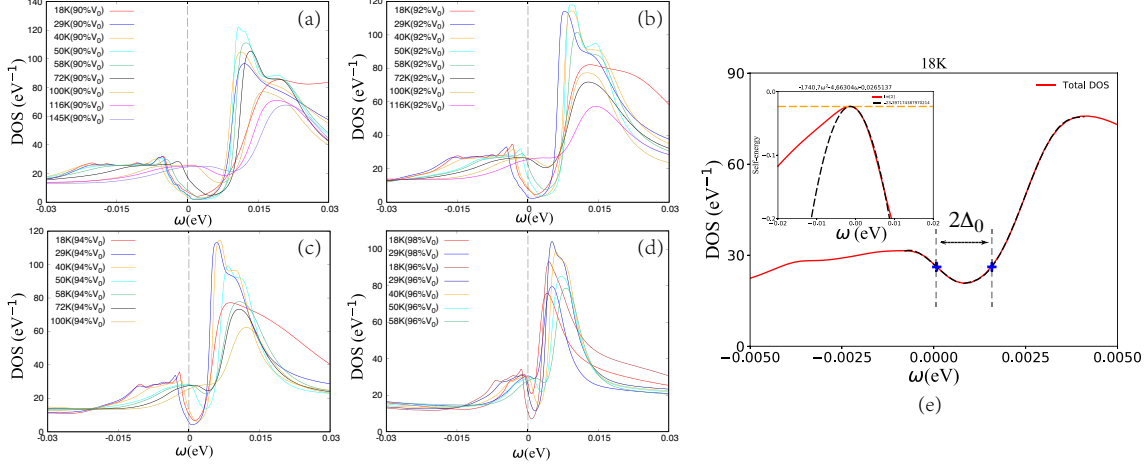
We illustrate the evolution of gap size for all the compressed cell-volume from high temperature (gap opening) to low temperature in Fig. 9 (a-d). It is worth noting that only at zero temperature the metal-insulator phase transition is well defined. At finite temperature, due to the incoherent scattering (the nonzero value of the imaginary part of self-energy),



Supplementary Figure. 7. Evolution of total energy and pressure versus various cell-volume. (a) Total energy calculated from DFT+DMFT. The total energy of equilibrium volume V_0 is set to zero. (b) The variation of hydrostatic pressure upon lattice compressing. The red star denotes the critical value of cell-volume for metal-insulator transition discussed in the main text. The grey dashed line are Murnaghan fitting to total energy and hydrostatic pressure.



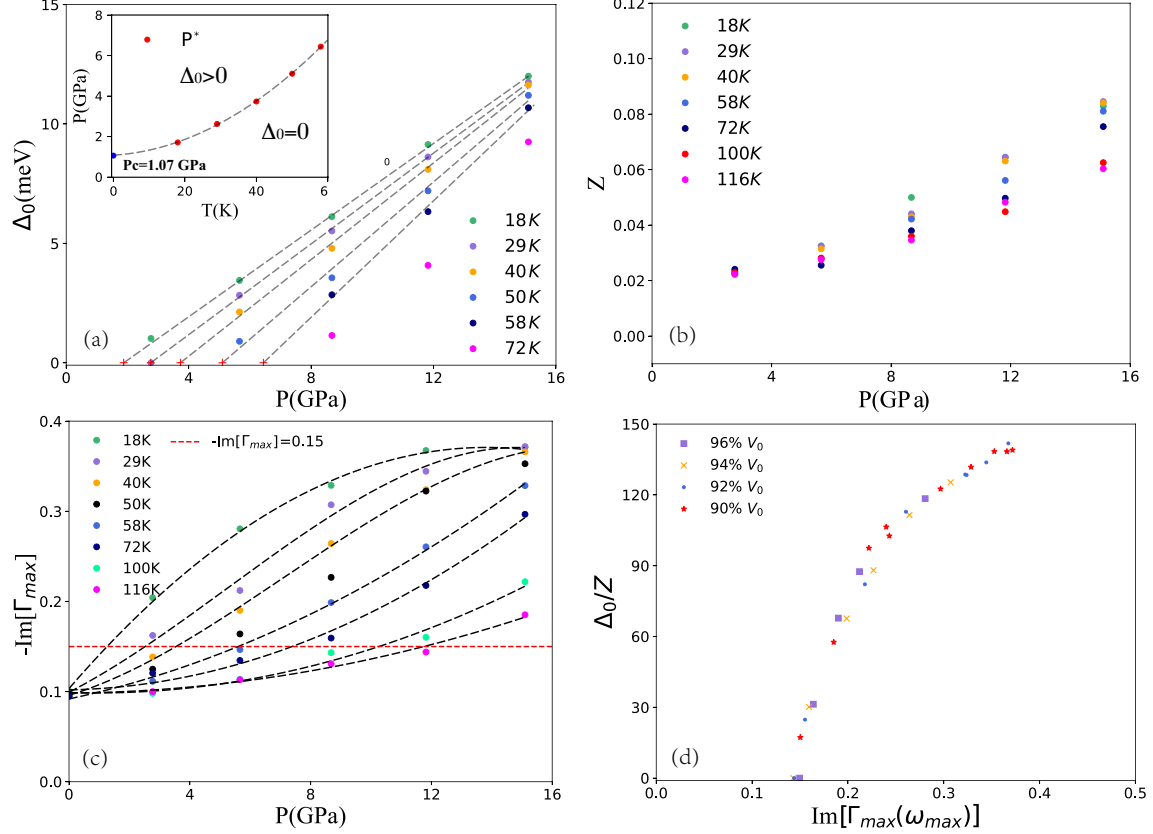
Supplementary Figure. 8. Temperature dependence of inverse local magnetic susceptibility for various compressed cell-volumes with error bars. The red dashed lines are linear fittings. The characteristic temperatures T^* are marked with red arrow, in agree with the Fig. 4 in the main text. The error bar was evaluated from the last 5 DMFT iterations after the calculation was well converged.



Supplementary Figure. 9. Pressure and temperature dependent of local spectra density. (a-d) The local spectra density plot for 90% V_0 , 92% V_0 , 94% V_0 , 96% V_0 and 98% V_0 compressed compounds at various temperatures. The gap size are evaluated from the half height of the maximal intensity at the gap edge below E_F to the minimal intensity value inside the gap as mentioned in the main text. (e) The local spectra density 98% V_0 compressed cell-volume. The imaginary part of $\text{Im}[\Sigma_{5/2}]$ on real-frequency axis for the current system is illustrated in the inset of (e). The black dashed line are the least-square fitting of local spectra density and $\text{Im}[\Sigma_{5/2}]$ within the gap.

there is only a crossover region between the metallic region and insulating region. As shown in Fig. 9 (e), although the gap already opens at 18 K for 98% V_0 , the system is still in the crossover region instead of the insulating region, since the imaginary part of self-energy ($\Sigma_0 \sim 26.5$ meV, defined in Fig. 6) is much larger than the gap size $2\Delta_0 \sim 2$ meV.

The pressure evolution of gap size Δ_0 is shown in Fig. 10 (a). In general, Δ_0 displays linear pressure dependence within the low temperature region ($T \leq 58$ K), similar to the observation in $\text{Ce}_3\text{Bi}_4\text{Pt}_3$ experimentally [12]. When the temperature further increases, the Δ_0 - P curve deviates away from the linear behavior. This is possibly due to the thermal effect. By extrapolating to $\Delta_0 = 0$, we define the gap opening pressure P^* , below which the system can be in the metallic regime or the crossover regime, rather than in the insulating phase. Therefore, the characteristic P^* is the lower limit pressure, where the system begins to enter the insulating regime from the metallic side when P increases at a specific temperature. Correspondingly, for a certain pressure, this specific temperature is the upper limit temperature T_2 mentioned in the main text. In the inset of Fig. 10 (a), P^* was fitted



Supplementary Figure. 10. Temperature and pressure dependent gap Δ_0 , renormalized factor Z and hybridization function. (a) The pressure dependence of gap Δ_0 . Δ_0 was linearly fitted as a function of pressure in the temperature range from 18 K to 58 K. The characteristic P^* at which $\Delta_0 = 0$ were marked with red plus. In the inset, P^* was fitted as a function of temperatures marked with dashed line. (b) The temperature and pressure dependence of quasiparticle weight Z ($m^*/m = Z^{-1} = 1 - \frac{\partial \text{Re}[\Sigma(\omega)]}{\partial \omega}$). (c) The imaginary part of hybridization function $-\text{Im}[\Gamma(\omega)]$ at its peak value vs pressure from 18 K to 116 K. $\omega_{\max}$ is the corresponding frequency, where $-\text{Im}[\Gamma(\omega)]$ reaches the maximal amplitude $-\text{Im}[\Gamma_{\max}(\omega)]$. The values of $-\text{Im}[\Gamma_{\max}(\omega)]$ at $P = 0$ were from our previous calculation [19]. The red dashed line marks $-\text{Im}[\Gamma_{\max}(\omega)] = 0.15$ eV, where the Δ_0 disappears as shown in (d). (d) The unrenormalized gap Δ_0/Z vs $-\text{Im}[\Gamma_{\max}(\omega)]$ for various compressed cell-volume. Δ_0/Z vanishes at $-\text{Im}[\Gamma_{\max}(\omega)] \approx 0.15$ eV.

parabolically as function of T . When T approaches 0 K, the thermal effect diminishes and P^* should also approach the critical pressure, P_c , at 0 K. Our fitting yields $P^* = 1.07$ GPa at 0 K. In the main text, we show the corresponding variation of characteristic T_2 as a function of cell-volume in the inset of Fig. 4.

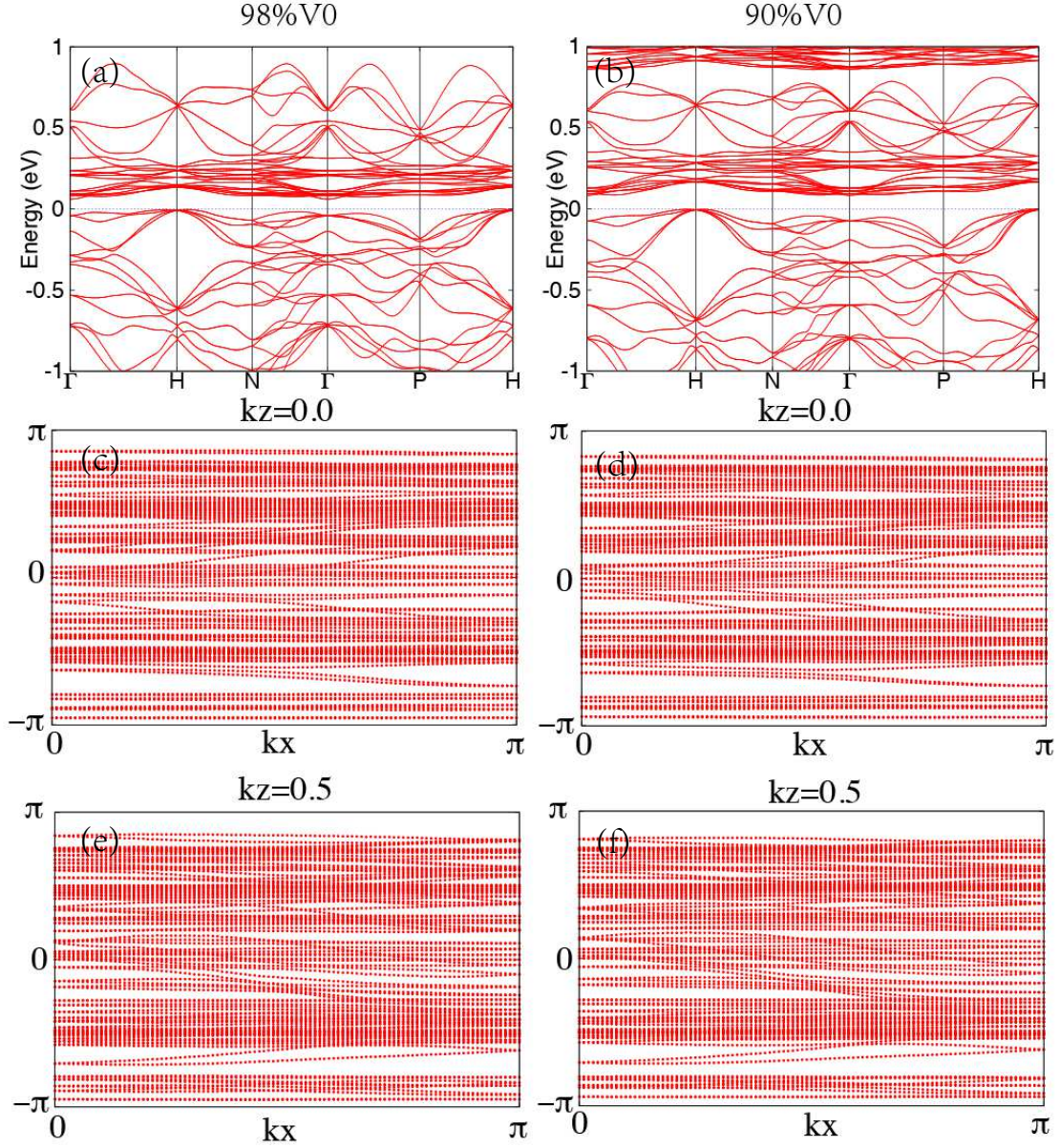
Supplementary Table. I. List of total energy E_0 and pressure P for 90%, 92%, 94%, 96% and 98% V_0 at 29 K. The total energy of equilibrium volume V_0 is set to zero. The values inside (outside) the bracket were fitted with Murnaghan equation of state (Birch–Murnaghan equation of state).

	90% V_0	92% V_0	94% V_0	96% V_0	98% V_0	V_0
E_0 (eV)	2.680 (2.680)	1.776 (1.775)	1.053 (1.053)	0.524 (0.524)	0.147 (0.147)	0.000 (0.000)
P (GPa)	15.10 (15.02)	11.82 (11.87)	8.68 (8.77)	5.66 (5.76)	2.77 (2.83)	0.00 (0.00)

Figure 10 (b) shows the temperature and pressure dependence of quasiparticle weight Z . In Fig. 10 (c), the maximal amplitude of hybridization function $-\text{Im}[\Gamma_{max}(\omega)]$ at ω_{max} around the Fermi level was plotted as the function of pressure at $T=18$ K, 29 K, 40 K, 50 K, 58 K, 72 K, 100 K and 116 K. The values of $-\text{Im}[\Gamma_{max}(\omega)]$ at ambient pressure were obtained from Ref. [19]. The pressure dependence of $-\text{Im}[\Gamma_{max}(\omega)]$ evolves from concave tendency at high temperature to convex tendency at low temperature. In Fig. 10 (d), we show that the unrenormalized gap (Δ_0/Z) size continuously approaches zero as the maximal amplitude of $-\text{Im}[\Gamma_{max}(\omega)]$ decreases for various compressed cell-volume. The critical value of $-\text{Im}[\Gamma_{max}(\omega)] \approx 0.15$ eV, where the gap disappears. In Fig. 10 (c), the critical value of $-\text{Im}[\Gamma_{max}(\omega)]$ was marked with red dashed line, below which the gap vanishes. The corresponding critical pressure P for the disappearance of gap at 18 K is around 1.26 GPa. As the temperature further decreases, P decreases as well. When the temperature approaches zero, P is expected in the range between 0 to 1.26 GPa, where the metal-insulator transition occurs.

5. Topological property

The topological property of current system can be described with topological Hamiltonian $h_t(\mathbf{k}) = h_0(\mathbf{k}) + \Sigma(0, \mathbf{k})$, which is encoded in zero frequency [27, 28]. By extrapolating to zero temperature, we can obtain the zero frequency self-energy $\Sigma(0, \mathbf{k})$ when $T \rightarrow 0$. In Fig. 11 (a-b), we show the energy spectra of topological Hamiltonian for 98% V_0 and 90% V_0 , respectively. It is worth mentioning that the energy spectra of h_t is not exactly the quasiparticle excitation spectra but the topological property of interacting system is correctly captured by h_t [28]. The evolution of Wannier charge center was calculated with the aforementioned topological Hamiltonian h_t for all the occupied states with Wilson-loop



Supplementary Figure. 11. Energy spectra of topological Hamiltonian and the evolution of Wannier charge center. (a-b) The spectra of topological Hamiltonian $H_t = H_0 + \Sigma(\omega = 0)$ for $98\%V_0$ and $90\%V_0$, respectively, where $\Sigma(\omega = 0)$ is the zero frequency self-energy extrapolated to zero temperature. (c-f) The corresponding evolution of Wannier charge center for the occupied states at $\mathbf{k}_z=0.0$ and π plane.

approach [29]. In either 98% V_0 or 90% V_0 system, the evolution pattern is trivial, indicating the normal insulating behavior of current system.

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